

# RQK0302GGDQA

Silicon N Channel MOS FET  
Power Switching

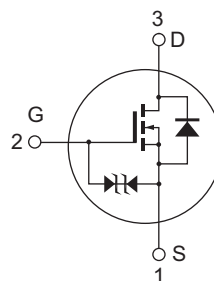
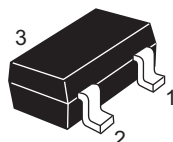
R07DS0305EJ0600  
Rev.6.00  
Jan 10, 2014

## Features

- Low on-resistance  
 $R_{DS(on)} = 92\text{ m}\Omega$  typ ( $V_{GS} = 10\text{ V}$ ,  $I_D = 1.3\text{ A}$ )
- Low drive current
- High speed switching
- 4.5 V gate drive

## Outline

RENESAS Package code: PLSP0003ZB-A  
(Package name: MPAK)



1. Source
2. Gate
3. Drain

Note: Marking is "GG".

## Absolute Maximum Ratings

( $T_a = 25^\circ\text{C}$ )

Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{DSS}$	30	V
Gate to source voltage	$V_{GSS}$	$\pm 20$	V
Drain current	$I_D$	2.7	A
Drain peak current	$I_{D(Pulse)}$ <sup>Note1</sup>	5	A
Body - drain diode reverse drain current	$I_{DR}$	2.7	A
Channel dissipation	$P_{ch}$ <sup>Note2</sup>	0.8	W
Channel temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

Notes: 1.  $PW \leq 10\ \mu\text{s}$ , duty cycle  $\leq 1\%$

2. When using the glass epoxy board (FR-4:  $40 \times 40 \times 1\text{ mm}$ )

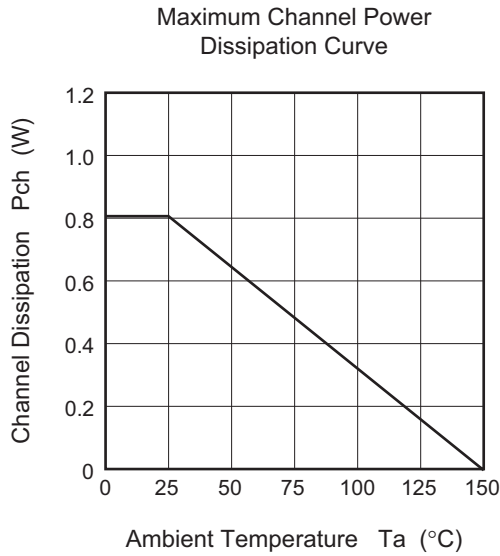
## Electrical Characteristics

(Ta = 25°C)

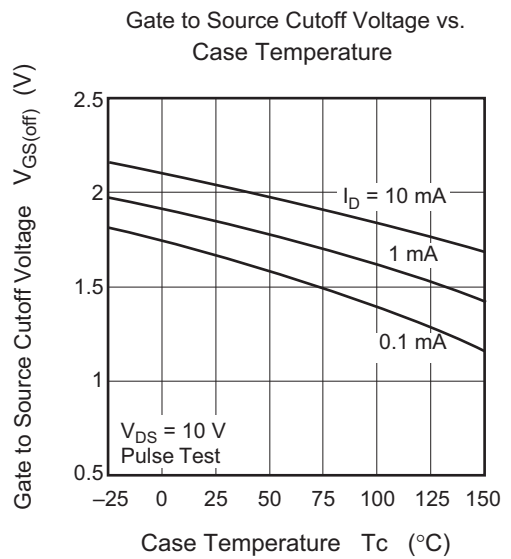
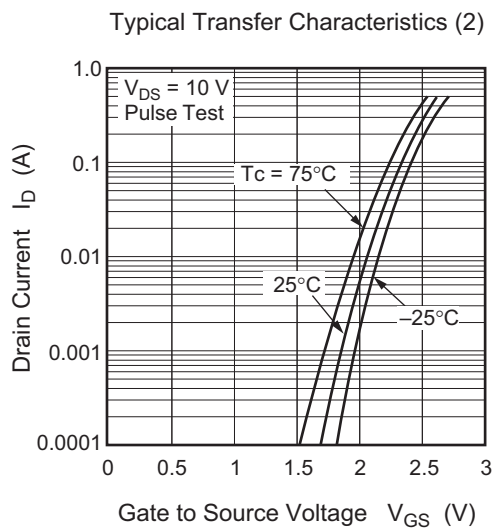
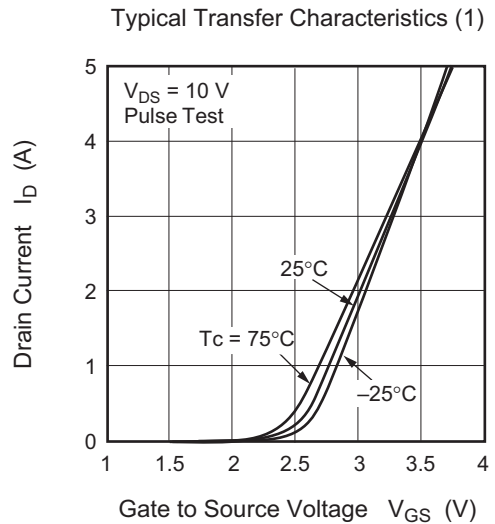
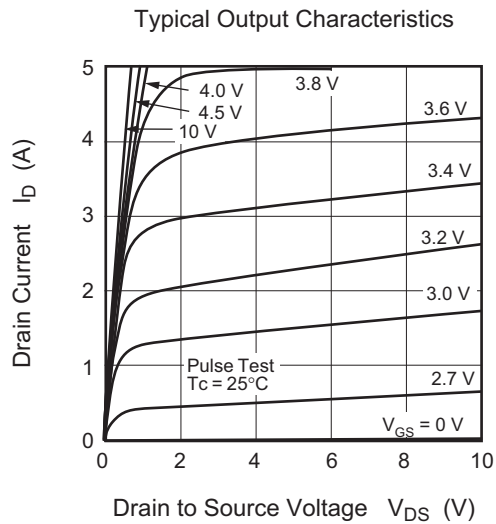
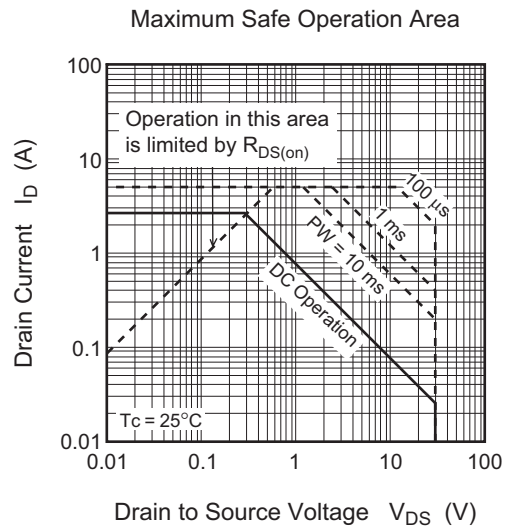
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	30	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	$\pm 20$	—	—	V	$I_G = \pm 100 \mu\text{A}, V_{DS} = 0$
Gate to source leak current	$I_{GSS}$	—	—	$\pm 10$	$\mu\text{A}$	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Drain to source leak current	$I_{DSS}$	—	—	1	$\mu\text{A}$	$V_{DS} = 30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	—	2.0	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Drain to source on state resistance	$R_{DS(on)}$	—	92	115	$\text{m}\Omega$	$I_D = 1.3 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note3}}$
	$R_{DS(on)}$	—	122	171	$\text{m}\Omega$	$I_D = 1.3 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note3}}$
Forward transfer admittance	$ y_{fs} $	2.1	3.5	—	S	$I_D = 1.3 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note3}}$
Input capacitance	$C_{iss}$	—	175	—	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$ $f = 1 \text{ MHz}$
Output capacitance	$C_{oss}$	—	34	—	pF	
Reverse transfer capacitance	$C_{rss}$	—	15	—	pF	
Turn - on delay time	$t_{d(on)}$	—	9.5	—	ns	$I_D = 1 \text{ A}, V_{GS} = 10 \text{ V},$ $R_L = 10 \Omega, R_g = 4.7 \Omega$
Rise time	$t_r$	—	37	—	ns	
Turn - off delay time	$t_{d(off)}$	—	38	—	ns	
Fall time	$t_f$	—	8.2	—	ns	
Total gate charge	$Q_g$	—	3.3	—	nC	$V_{DD} = 10 \text{ V}, V_{GS} = 10 \text{ V},$ $I_D = 2.7 \text{ A}$
Gate to source charge	$Q_{gs}$	—	0.6	—	nC	
Gate to drain charge	$Q_{gd}$	—	0.5	—	nC	
Body - drain diode forward voltage	$V_{DF}$	—	0.9	—	V	$I_F = 1.5 \text{ A}, V_{GS} = 0^{\text{Note3}}$

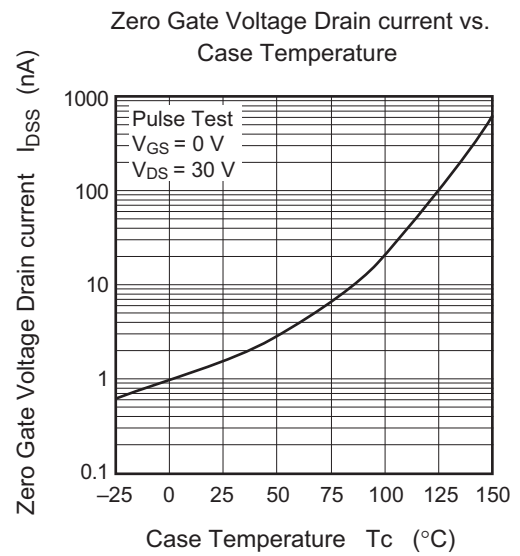
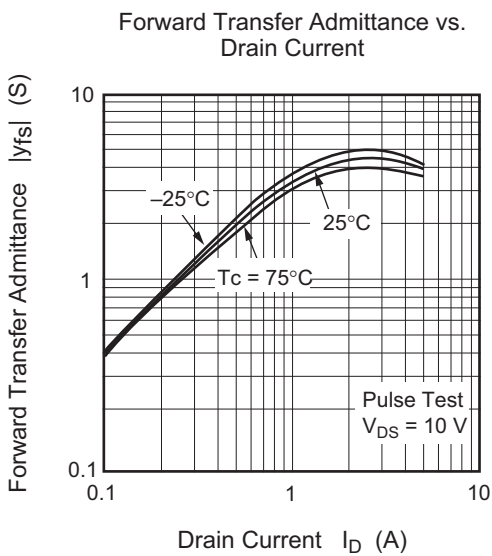
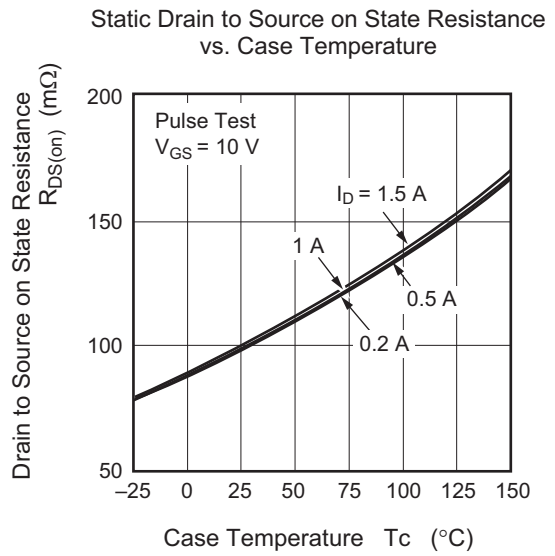
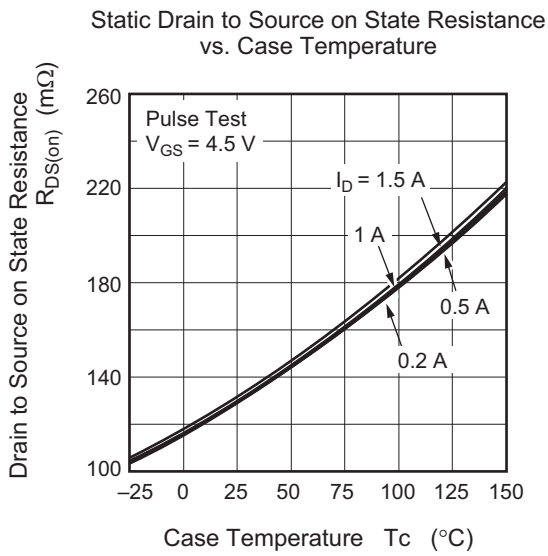
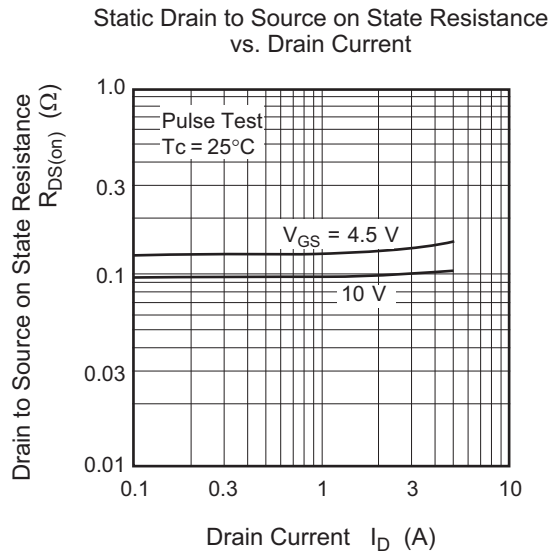
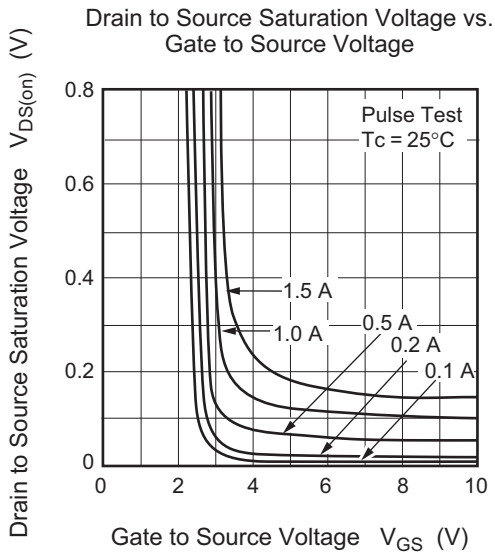
Notes: 3. Pulse test

Main Characteristics

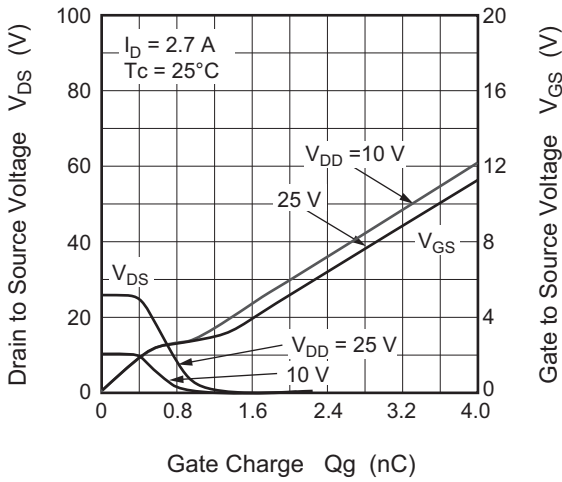


\*When using the glass epoxy board (FR-4: 40 × 40 × 1 mm)

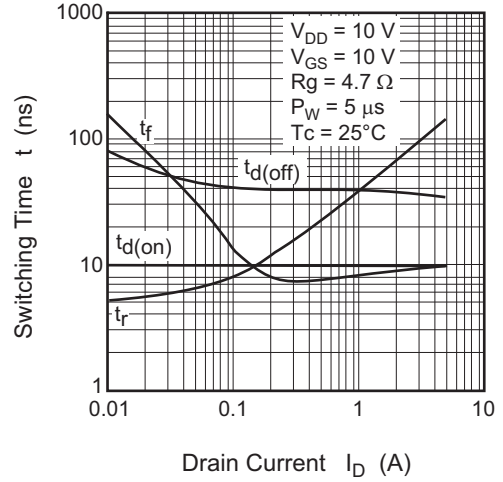




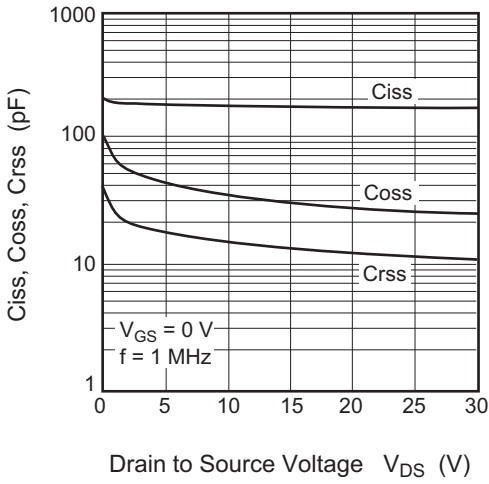
Dynamic Input Characteristics



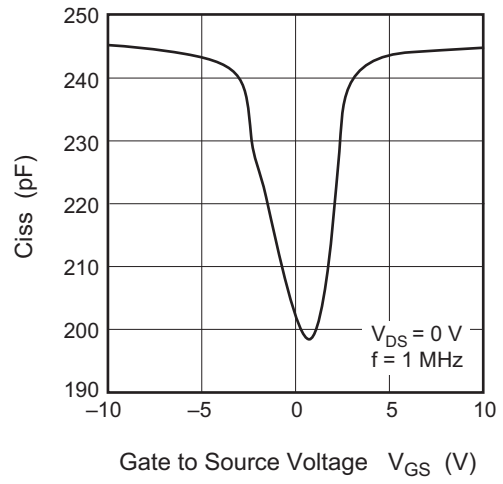
Switching Characteristics



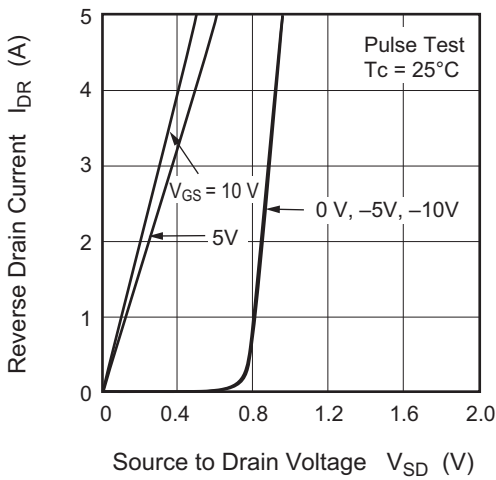
Typical Capacitance vs. Drain to Source Voltage



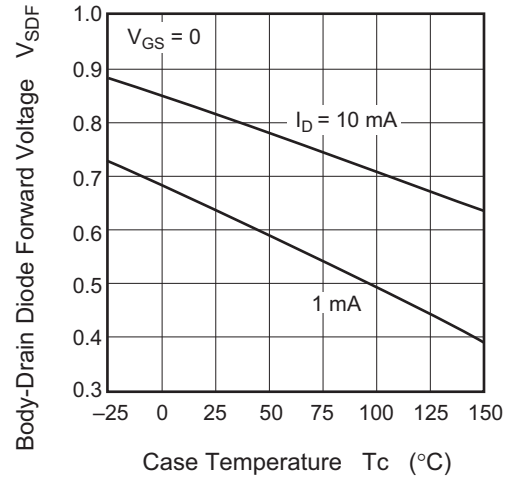
Input Capacitance vs. Gate to Source Voltage



Reverse Drain Current vs. Source to Drain Voltage

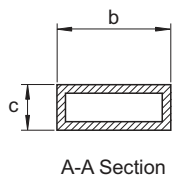
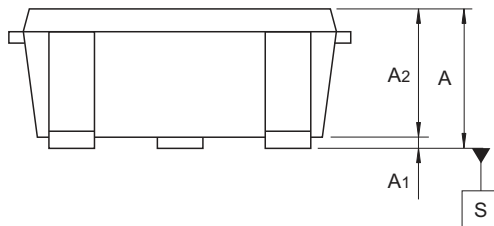
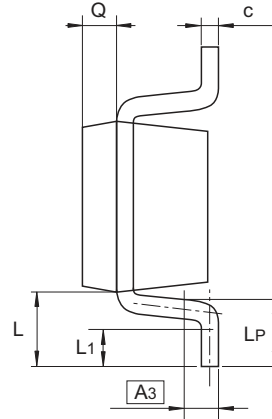
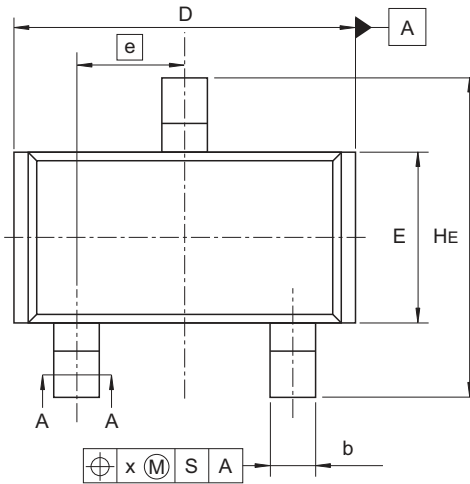


Body-Drain Diode Forward Voltage vs. Case Temperature



Package Dimensions

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
SC-59A	PLSP0003ZB-A	MPAK(T) / MPAK(T)V	0.011



Reference Symbol	Dimensions in millimeters		
	Min	Nom	Max
A	1.0	—	1.3
A1	0	—	0.1
A2	1.0	1.1	1.2
A3	—	0.25	—
b	0.35	0.4	0.5
c	0.1	0.16	0.26
D	2.7	—	3.1
E	1.35	1.5	1.65
e	—	0.95	—
HE	2.2	2.8	3.0
L	0.35	—	0.75
L1	0.15	—	0.55
LP	0.25	—	0.65
x	—	—	0.05
Q	—	0.3	—

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### Ordering Information

Orderable Part Number	Quantity	Shipping Container
RQK0302GGDQATL-H	3000 pcs.	φ178 mm reel, 8 mm Emboss taping

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2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A.  
Tel: +1-408-586-6000, Fax: +1-408-588-6130

**Renesas Electronics Canada Limited**  
1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada  
Tel: +1-905-898-5441, Fax: +1-905-898-3220

**Renesas Electronics Europe Limited**  
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.  
Tel: +44-1628-651-700, Fax: +44-1628-651-804

**Renesas Electronics Europe GmbH**  
Arcadiastrasse 10, 40472 Düsseldorf, Germany  
Tel: +49-211-65030, Fax: +49-211-6503-1327

**Renesas Electronics (China) Co., Ltd.**  
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China  
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

**Renesas Electronics (Shanghai) Co., Ltd.**  
Unit 301, Tower A, Central Towers, 555 LanGao Rd., Putuo District, Shanghai, China  
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

**Renesas Electronics Hong Kong Limited**  
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong  
Tel: +852-2886-9318, Fax: +852 2886-9022/9044

**Renesas Electronics Taiwan Co., Ltd.**  
13F, No. 363, Fu Shing North Road, Taipei, Taiwan  
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

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80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre Singapore 339949  
Tel: +65-6213-0200, Fax: +65-6213-0300

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Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jin Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia  
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

**Renesas Electronics Korea Co., Ltd.**  
12F., 234 Teheran-ro, Gangnam-Gu, Seoul, 135-080, Korea  
Tel: +82-2-558-3737, Fax: +82-2-558-5141